

View Online at <https://aerobasegroup.com/nsn/5980-01-058-4856>

**Test Data Document:**

81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

**General Description:**

A gallium arsenide diode is optically coupled to a silicon npn phototransistor; led maximum ratings consist of 2v vr; 40ma if; 1a ip; 25 degrees c ta; phototransistor maximum ratings consist of 35v vceo; 35v vcbo; 4v vebo; 50ma ic; 300mw pt; 0.155 in. To 0.185 in. Maximum lg; 0.335 in. To 0.370 in. Maximum dia; 6 lead type terminals

**Specification Data:**

81349-mil-prf-19500/486 government specification

**Shelf Life:**

N/a

**Unit Of Measure:**

--

**Demilitarization:**

Yes - demil/mli

**Fig:**

A23900

**Mil-std (military Standard):**

Mil-prf-19500 spec.